

# SHINDENGEN

## General Purpose Rectifiers

SIL Bridges

**D2SB60L**

**600V 1.5A**

### FEATURES

- Thin Single In-Line Package
- High IFSM
- Applicable to Automatic Insertion

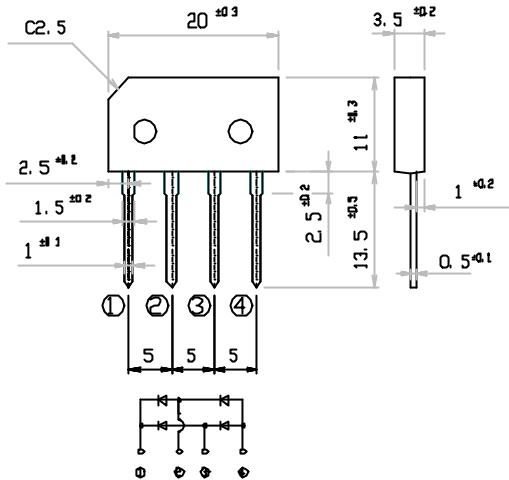
### APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommunication, Factory Automation

### OUTLINE DIMENSIONS

Case : 2S

Unit : mm



### RATINGS

Absolute Maximum Ratings (If not specified  $T_{J}=25^{\circ}\text{C}$ )

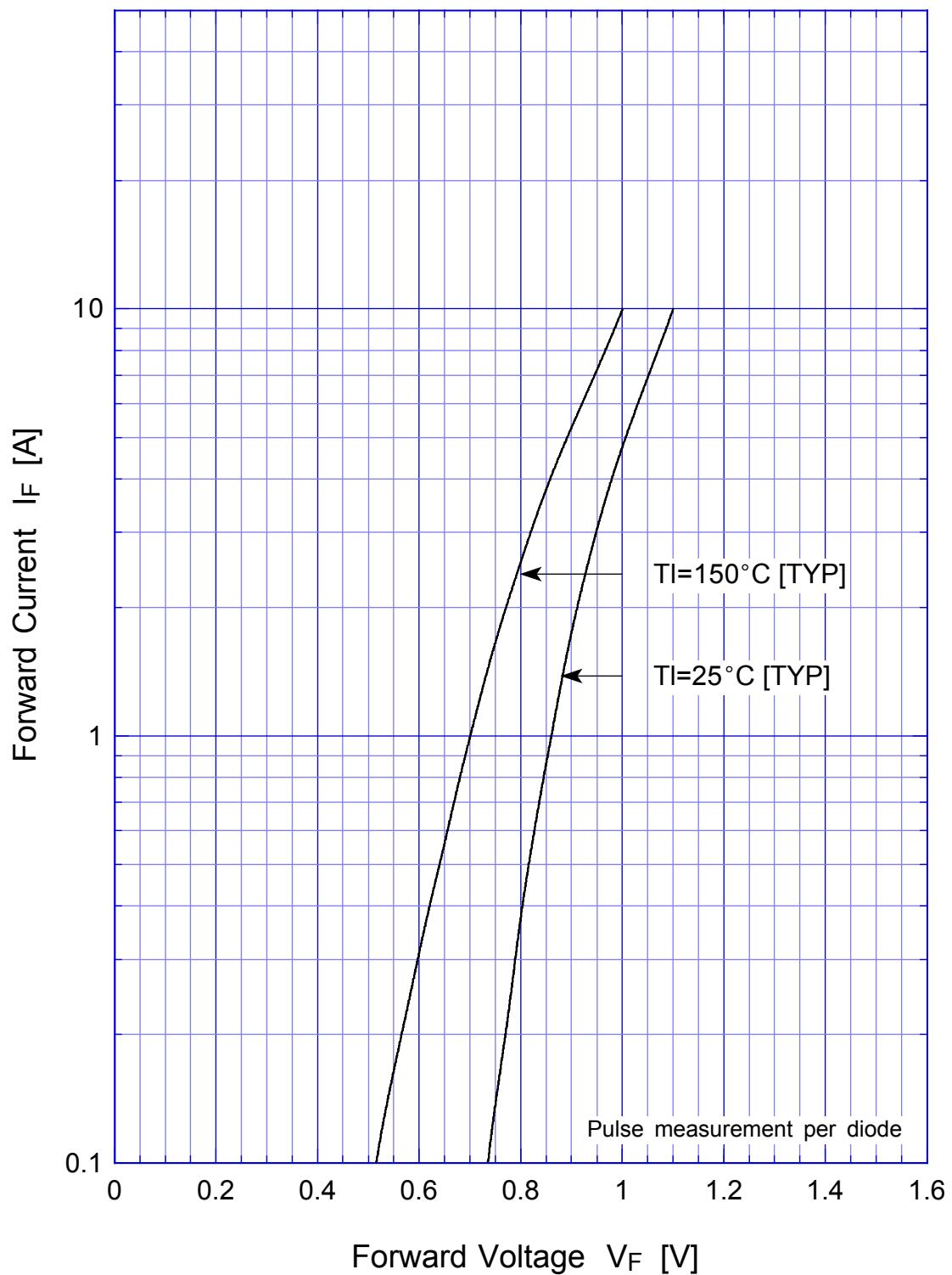
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	$T_{\text{stg}}$		-40 ~ 150	
Operating Junction Temperature	$T_j$		150	
Maximum Reverse Voltage	$V_{\text{RM}}$		600	V
Average Rectified Forward Current	$I_o$	50Hz sine wave, R-load, On glass-epoxy substrate, $T_a=25^{\circ}\text{C}$	1.5	A
Peak Surge Forward Current	$I_{\text{FSM}}$	50Hz sine wave, Non-repetitive 1cycle peak value, $T_j=25^{\circ}\text{C}$	120	A
Current Squared Time	$I^2t$	1ms $t < 10\text{ms}$ $T_j = 25^{\circ}\text{C}$	40	$\text{A}^2\text{s}$

Electrical Characteristics (If not specified  $T_{\text{J}}=25^{\circ}\text{C}$ )

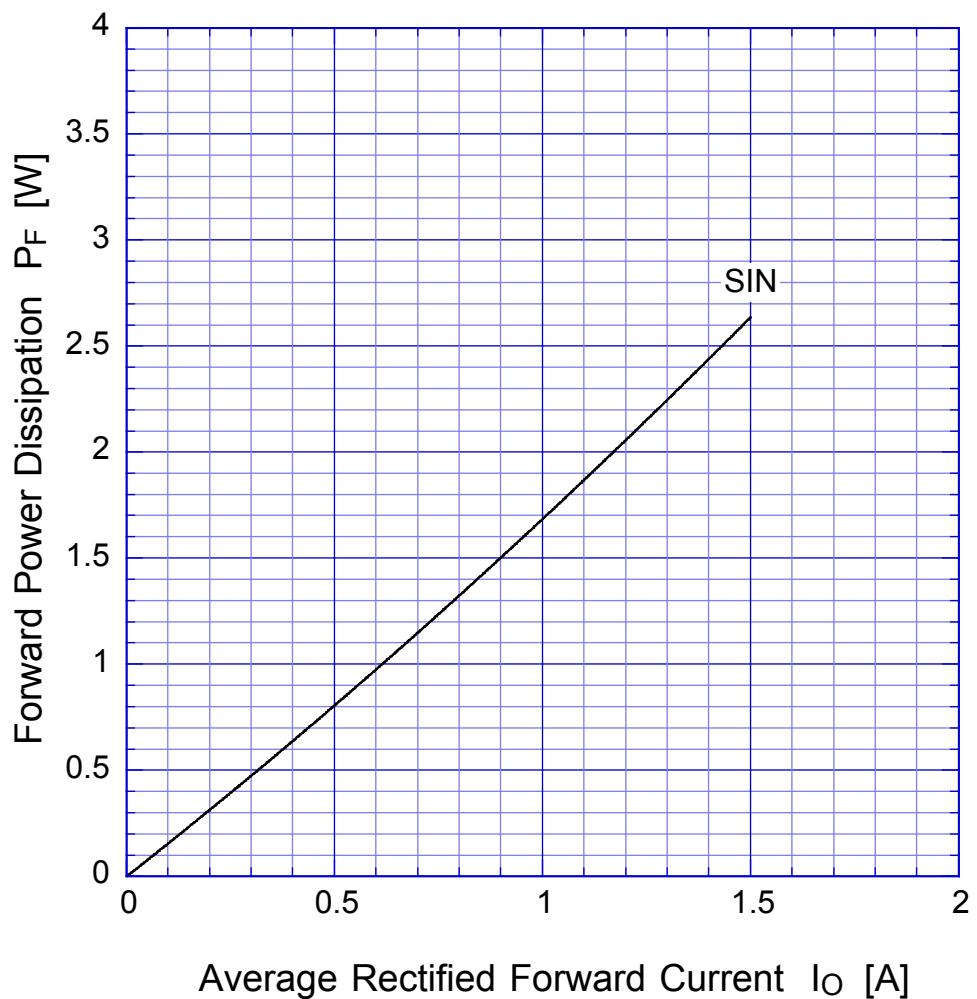
Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	$V_F$	$I_F=0.75\text{A}$ , Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	$I_R$	$V_R=V_{\text{RM}}$ , Pulse measurement, Rating of per diode	Max.10	$\mu\text{A}$
Reverse Recovery Time	$t_{\text{rr}}$	$I_F=0.1\text{A}$ , $I_R=0.1\text{A}$ , Rating of per diode	Max.10	$\mu\text{s}$
Thermal Resistance	$j_l$	junction to lead	Max.10	/W
	$j_a$	junction to ambient	Max.47	

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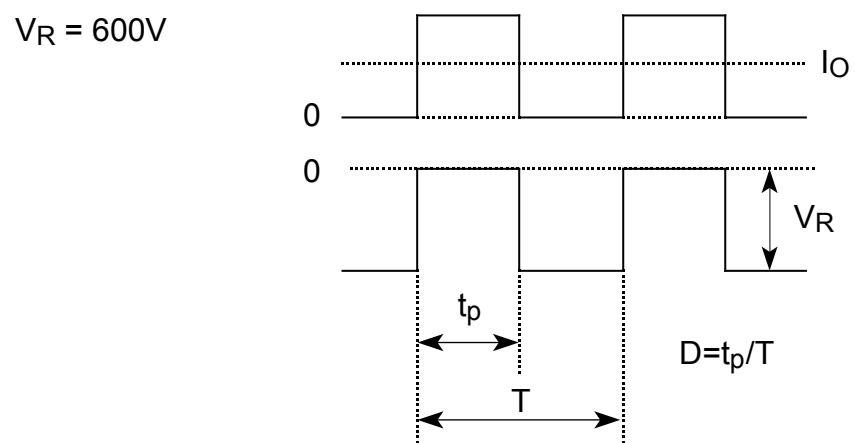
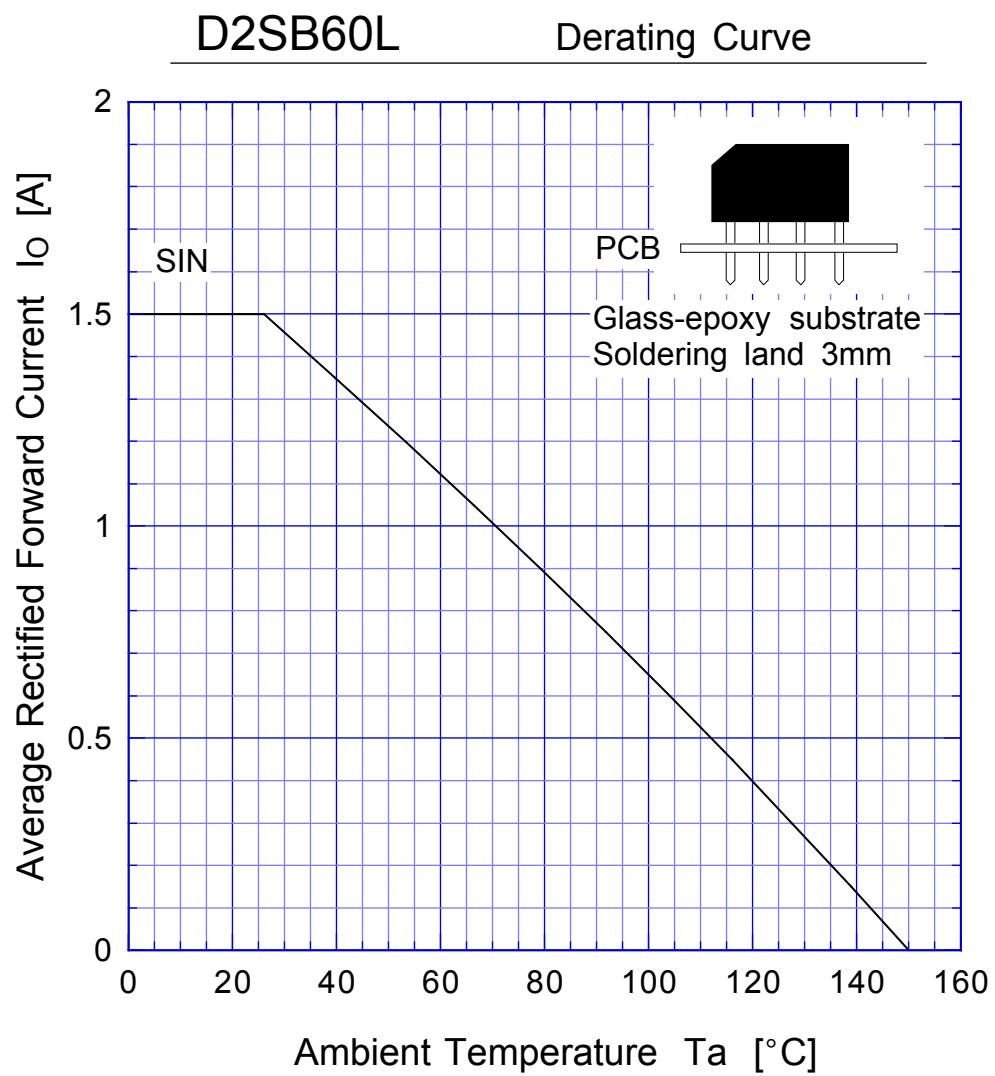
## Forward Voltage



## D2SB60L Forward Power Dissipation



$T_j = 150^\circ\text{C}$   
Sine wave



# D2SB60L

## Peak Surge Forward Capability

